NSN 5961-01-294-5792

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-294-5792 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 1.050 inches **Overall Width:** Between 0.250 inches and 0.375 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 375.0 collector to base voltage/static/emitter open and 300.0 collector-to-emitter substaining voltage, with specified circuit between base and emitter and 9.0 emitter to base voltage, static, collector open and 275.0 collector-to-emitter, substaining voltage, base open-circuited and 300.0 collector-to-emitter substaining voltage, resistance between base and emitter **Current Rating Per Characteristic:** 10.00 amperes zero-gate-voltage source current blank and 10.00 amperes zero-gate-voltage source current of standard range **Power Rating Per Characteristic:** 175.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No Fiig:

A110a0